

# AlGaAs Bragg reflection waveguides for hybrid quantum photonic devices





Lorenzo Lazzari<sup>1,2,3</sup>, Jérémie Schuhmann<sup>1,2,3</sup>, Aristide Lemaître<sup>2</sup>, Maria I. Amanti<sup>1</sup>, Frédéric Boeuf<sup>3</sup>, Fabrice Raineri<sup>2</sup>, Florent Baboux<sup>1</sup>, and Sara Ducci<sup>1</sup>

<sup>1</sup> Laboratoire Matériaux et Phénomènes Quantiques, Université Paris Cité, 75013 Paris, France <sup>2</sup> Centre de Nanosciences et de Nanotechnologies, Université Paris-Saclay, 91120 Palaiseau, France <sup>3</sup> ST Microelectronics, 38190 Crolles, France





# Towards hybridization

Integrated quantum photonics goal: on-chip generation, manipulation, distribution and detection of qubits

## Cavity-coupled quantum emitter esonator-coupled quantum memor uperconducting single-photon detecto ------

Integrating different platforms to leverage the complementary assets <u>SOI</u> AlGaAs Leader in complex Incompatibility with CMOS; complex linear integrated × components still optical components;

### Challenges

SOI/AIGaAs wafer bonding, solving the constraints deriving from the lattice mismatch; GaAs substrate removal, waveguide patterning and alignment between the two platforms

#### Perspectives

Integrated hybrid electrically driven photonpair source





Efficient, wide-band, polarisation insensitive, fabrication friendly, robust and low footprint optical mode coupling design, compatible with existing SOI stacks and industry standards

Conservation of the produced bi-photon state properties (JSI, entanglement visibility, degree of indistinguishability) from one photonic circuit to the other



Financial support:





Cifre